LE B P3W 01

OSRAM OSTAR® Projection Power

OSRAM OSTAR Projection Power is a high luminance LED for projection applications.



Applications

- Projection Home LED & Laser

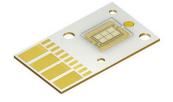
- Projection Professional LED & Laser

Features:

- Package: OSTAR High Power Projection
- Chip technology: UX:3
- Typ. Radiation: 120° (Lambertian emitter)
- Color: $\lambda_{dom} = 459 \text{ nm}$ (• blue)
- Corrosion Robustness Class: 3B
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)

Ordering Information

| Туре | Total radiant flux ¹⁾ Ι _F = 36000 mA Φ _e | Ordering Code |
|---------------------|---|---------------|
| LE B P3W 01-GZHZ-24 | 24000 45000 mW | Q65112A4108 |
| LE B P3W 01-GZHZ-VW | 24000 45000 mW | Q65112A4119 |





Maximum Ratings

| Parameter | Symbol | | Values |
|--|----------------------|------|----------|
| Operating Temperature | T _{op} | min. | -40 °C |
| | | max. | 125 °C |
| Storage Temperature | T _{stg} | min. | -40 °C |
| | | max. | 125 °C |
| Junction Temperature | T_{j} | max. | 150 °C |
| Forward Current | I _F | min. | 600 mA |
| T _J = 150 °C; all chips operated in parallel | | max. | 30000 mA |
| Forward Current pulsed D = 0.25 ; f = 240 Hz; $T_{_B}$ = 25 °C; all chips operated in parallel | I _{F pulse} | | 48000 mA |
| Surge Current tp \leq 10 µs; D = 0.1; T _J = 150 °C; all chips operated in parallel | I _{FS} | max. | 60000 mA |
| ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2) | V_{ESD} | | 2 kV |
| Reverse current ²⁾ | I _R | max. | 200 mA |



Characteristics

 T_{Board} = 25 °C; I_F = 36000 mA; f = 1000 Hz; t_{int} = 100 ms; D = 0.25; all chips operated in parallel

| Parameter | Symbol | | Values |
|---|-------------------------|------|---------------------------|
| Peak Wavelength | λ_{peak} | typ. | 455 nm |
| Dominant Wavelength 3) | λ _{dom} | min. | 444 nm |
| | donn | typ. | 459 nm |
| | | max. | 465 nm |
| Spectral bandwidth at 50% I _{rel,max} | $\Delta \lambda$ | typ. | 27 nm |
| Viewing angle at 50% ${\rm I_v}$ | 2φ | typ. | 120 ° |
| Radiating surface | A_{color} | typ. | 4.8 x 2.6 mm ² |
| Partial Flux acc. CIE 127:2007 4) | Φ _{E/V, 120°} | typ. | 0.82 |
| I _F = 36000 mA | | | |
| Forward Voltage ⁵⁾ | V _F | min. | 3.20 V |
| I _F = 36000 mA; all chips operated in parallel | · | typ. | 3.35 V |
| | | max. | 4.30 V |
| Deviation of forward voltage of all chips | V _F | max. | 135 mV |
| Reverse voltage (ESD device) | $V_{R ESD}$ | min. | 45 V |
| Reverse voltage 2) | V _R | max. | 1.2 V |
| I _R = 20 mA | | | |
| Real thermal resistance junction/board | $R_{thJB real}$ | typ. | 0.5 |
| Electrical thermal resistance junction/board | R _{thJB elec.} | typ. | 0.38 |
| with efficiency η_e = 24 % | | | |

Brightness Groups

| Group | Total radiant flux ¹⁾ I _F = 36000 mA min. Φ_{e} | Total radiant flux ¹⁾ I _F = 36000 mA max. Φ_{e} |
|-------|---|---|
| GZ | 24000 mW | 28000 mW |
| HX | 28000 mW | 33000 mW |
| HY | 33000 mW | 39000 mW |
| HZ | 39000 mW | 45000 mW |

Wavelength Groups

| Group | Dominant Wavelength ³⁾ min. | Dominant Wavelength ³⁾ max. | |
|-------|--|--|--|
| | λ_{dom} | λ _{dom} | |
| V | 444 nm | 448 nm | |
| W | 448 nm | 452 nm | |
| 2 | 452 nm | 456 nm | |
| 3 | 456 nm | 460 nm | |
| 4 | 460 nm | 465 nm | |

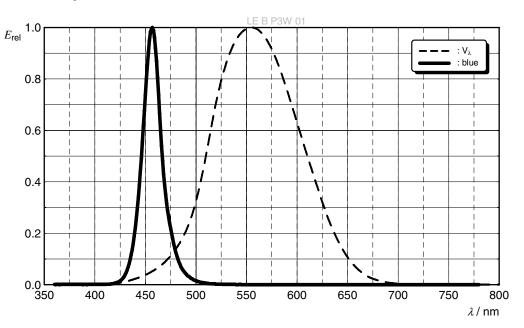
Group Name on Label

| Example: GZ-2 Brightness | Wavelength |
|-----------------------------|------------|
| GZ | 2 |



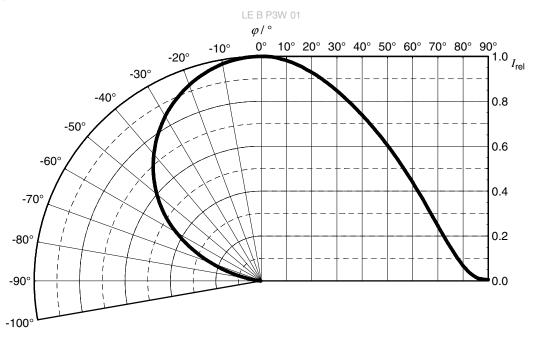
Relative Spectral Emission⁴⁾

 $\rm E_{\rm rel}$ = f (\lambda); $\rm I_{\rm F}$ = 36000 mA; $\rm T_{\rm J}$ = 25 °C; all chips operated in parallel



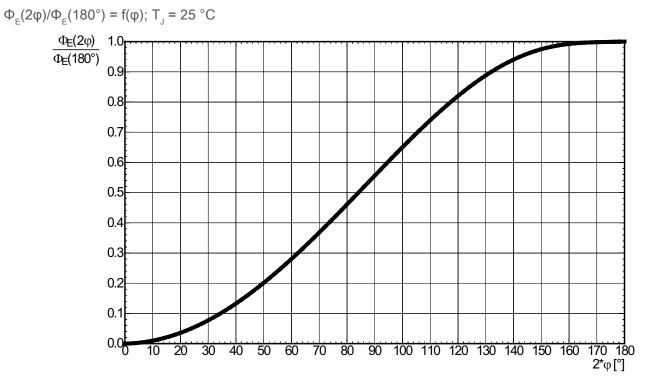
Radiation Characteristics⁴⁾

I_{rel} = f (φ); T_J = 25 °C





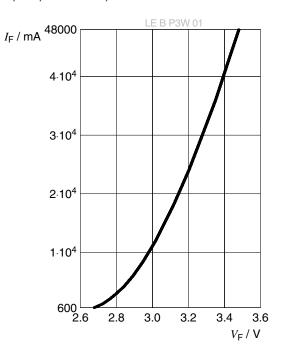
Relative Partial Flux⁴⁾





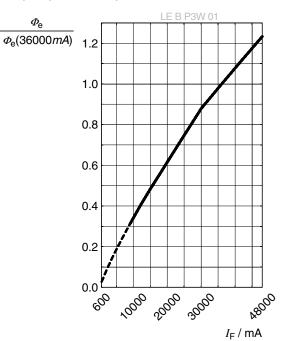
Forward current ^{4), 6)}

 $I_{_{F}} = f(V_{_{F}}); T_{_{J}} = 25 \text{ °C};$ all chips operated in parallel



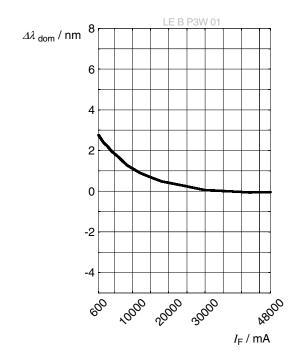
Relative Radiant Power 4), 6)

 $\Phi_{\rm E}/\Phi_{\rm E}(36000 \text{ mA}) = f(I_{\rm F}); T_{\rm J} = 25 \text{ °C};$ all chips operated in parallel



Dominant Wavelength⁴⁾

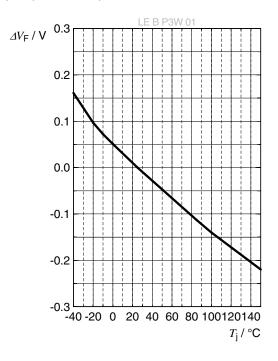
$$\label{eq:lambda} \begin{split} \Delta\lambda_{\rm dom} &= f(I_{\rm F}); \ T_{\rm J} = 25 \ ^{\circ}{\rm C}; \\ \text{all chips operated in parallel} \end{split}$$





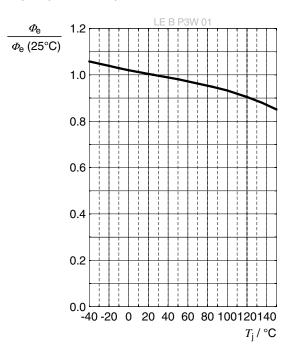
Forward Voltage ⁴⁾

 $\Delta V_F = V_F - V_F (25 \text{ °C}) = f(T_J); I_F = 36000 \text{ mA};$ all chips operated in parallel



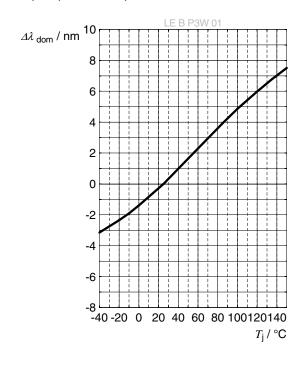
Relative Radiant Power⁴⁾

 $\Phi_{\rm E}/\Phi_{\rm E}(25 \ ^{\circ}{\rm C}) = f(T_{\rm J}); I_{\rm F} = 36000 \text{ mA};$ all chips operated in parallel



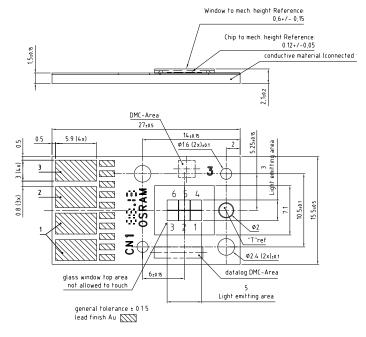
Dominant Wavelength ⁴⁾

$$\label{eq:lambda} \begin{split} \Delta\lambda_{\rm dom} &= \lambda_{\rm dom} - \lambda_{\rm dom} (25~^\circ C) = f(T_{\rm _J});~I_{\rm _F} = 36000~mA; \\ \text{all chips operated in parallel} \end{split}$$





Dimensional Drawing 7)



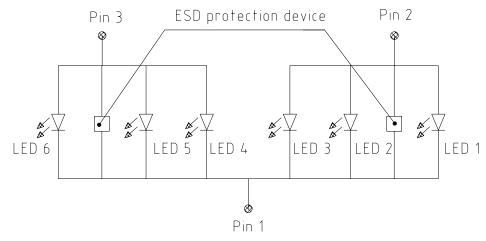
C67062-A0162-A1KA 01

Further Information:

| Approximate Weight: | 5,000.0 mg |
|---------------------|---|
| Corrosion test: | Class: 3B Test condition: 40°C / 90 % RH / 15 ppm H ₂ S / 14 days (stricter than IEC 60068-2-43) |
| ESD advice: | The device is protected by ESD device which is connected in parallel to the Chip. |
| Notes: | Package not suitable for any kind of wet cleaning or ultrasonic cleaning. |



Electrical Internal Circuit

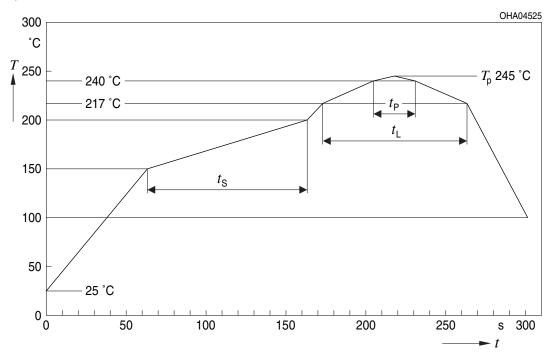


1: cathode 2: anode Chip 1, 2 and 3 3: anode Chip 4, 5 and 6



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020E



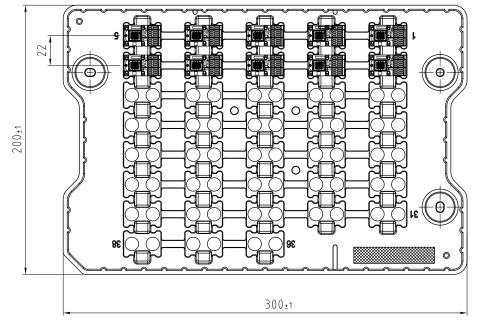
| Profile Feature | Symbol | | -Free (SnAgCu) Ass | - | Unit |
|--|----------------|---------|--------------------|---------|------|
| | | Minimum | Recommendation | Maximum | |
| Ramp-up rate to preheat ^{•)} 25 °C to 150 °C | | | 2 | 3 | K/s |
| Time t _s T _{smin} to T _{smax} | t _s | 60 | 100 | 120 | S |
| Ramp-up rate to peak $^{*)}$ T $_{\rm Smax}$ to T $_{\rm P}$ | | | 2 | 3 | K/s |
| Liquidus temperature | TL | | 217 | | °C |
| Time above liquidus temperature | t | | 80 | 100 | S |
| Peak temperature | Τ _Ρ | | 245 | 260 | °C |
| Time within 5 °C of the specified peak temperature T_p - 5 K | t _P | 10 | 20 | 30 | S |
| Ramp-down rate* T _P to 100 °C | | | 3 | 6 | K/s |
| Time 25 °C to T _P | | | | 480 | S |

All temperatures refer to the center of the package, measured on the top of the component * slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



LE B P3W 01

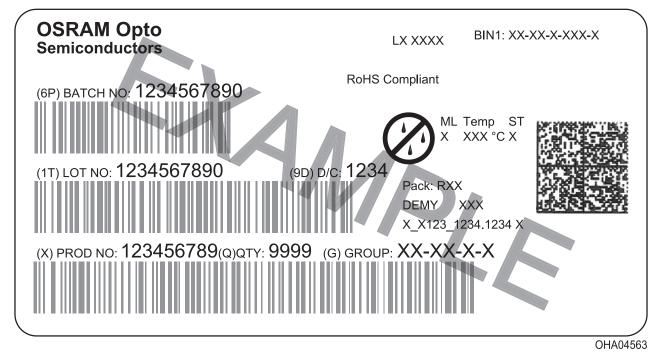
Taping 7)



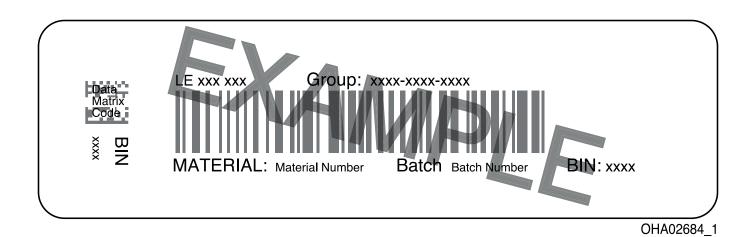
C63062-A4389-B10-01



Barcode-Product-Label (BPL)



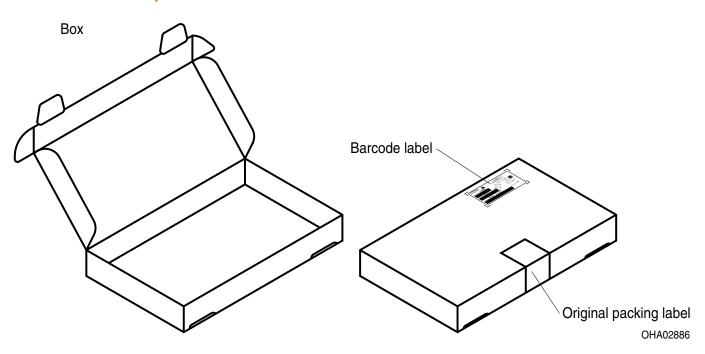
Barcode-Tray-Label (BTL)



Not for new design



Schematic Transportation Box 7)

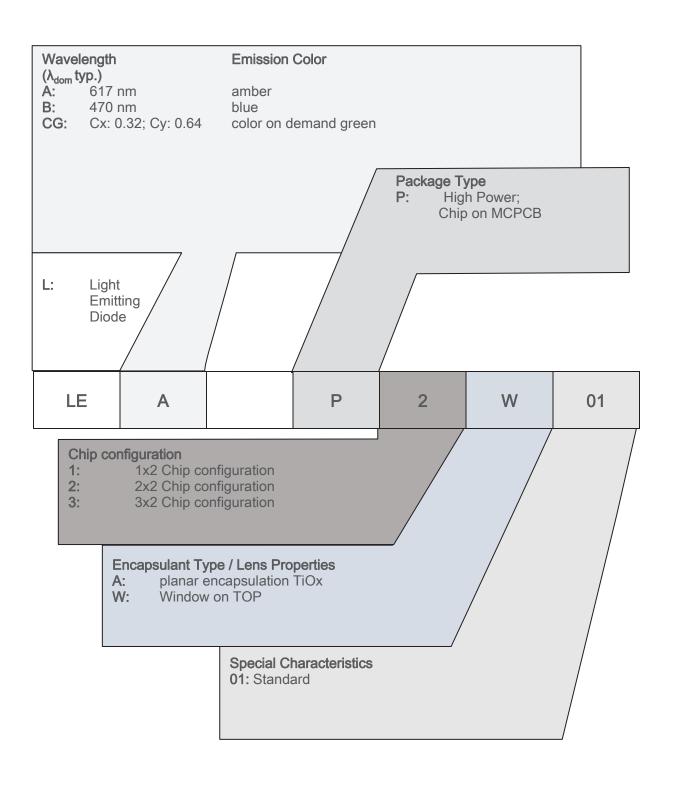


Dimensions of Transportation Box

| Width | Length | Height | |
|------------|-----------|-----------|--|
| 333 ± 5 mm | 218 ±5 mm | 28 ± 5 mm | |
| 337 ± 5 mm | 218 ±5 mm | 63 ± 5 mm | |



Type Designation System





Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into the class **moderate risk (exposure time 0.25 s)**. Under real circumstances (for exposure time, conditions of the eye pupils, observation distance), it is assumed that no endangerment to the eye exists from these devices. As a matter of principle, however, it should be mentioned that intense light sources have a high secondary exposure potential due to their blinding effect. When looking at bright light sources (e.g. headlights), temporary reduction in visual acuity and afterimages can occur, leading to irritation, annoyance, visual impairment, and even accidents, depending on the situation.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

For further application related information please visit www.osram-os.com/appnotes



Disclaimer

Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on the OSRAM OS website.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Product and functional safety devices/applications or medical devices/applications

OSRAM OS components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

OSRAM OS products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using OSRAM OS components in product safety devices/applications or medical devices/applications, buyer and/or customer has to inform the local sales partner of OSRAM OS immediately and OSRAM OS and buyer and /or customer will analyze and coordinate the customer-specific request between OSRAM OS and buyer and/or customer.



Glossary

- ¹⁾ Brightness: Brightness values are measured during a pulse train of 100 ms with a pulse width of 250 µs and a frequencey of 1 kHz, with an internal reproducibility of +/- 8 % and an expanded uncertainty of +/- 11 % (acc. to GUM with a coverage factor of k = 3). The peak brightness is calculated according to the pulse duration and frequency.
- ²⁾ Reverse Operation: This product is intended to be operated applying a forward current within the specified range. Applying any continuous reverse bias or forward bias below the voltage range of light emission shall be avoided because it may cause migration which can change the electro-optical characteristics or damage the LED.
- ³⁾ **Wavelength:** The wavelength is measured during a pulse train of 100 ms with a pulse width of 250 μ s and a frequencey of 1 kHz, with an internal reproducibility of ± 0,5 nm and an expanded uncertainty of ± 1 nm (acc. to GUM with a coverage factor of k=3).
- ⁴⁾ Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- ⁵⁾ **Forward Voltage:** The forward voltage is measured during a pulse of typical 250 μs, with an internal reproducibility of +/- 0,05 V and an expanded uncertainty of +/- 0,1 V (acc. to GUM with a coverage factor of k=3).
- ⁶⁾ **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- ⁷⁾ **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



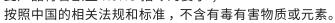
Revision History

| Version | Date | Change |
|---------|------------|--------------------|
| 1.2 | 2018-12-03 | New Layout |
| 1.3 | 2019-09-05 | Тгау |
| 1.4 | 2020-06-30 | Not for new design |



LE B P3W 01

Published by OSRAM Opto Semiconductors GmbHEU RoHS and China RoHS compliant productLeibnizstraße 4, D-93055 RegensburgEU RoHS and China RoHS compliant productwww.osram-os.com © All Rights Reserved.此产品符合欧盟 RoHS 指令的要求;





e